

# ENERGY-EFFICIENT GRID-CONNECTED BATTERY CONDITIONER

## Presentation of Green PE Pilot Results – January 2019



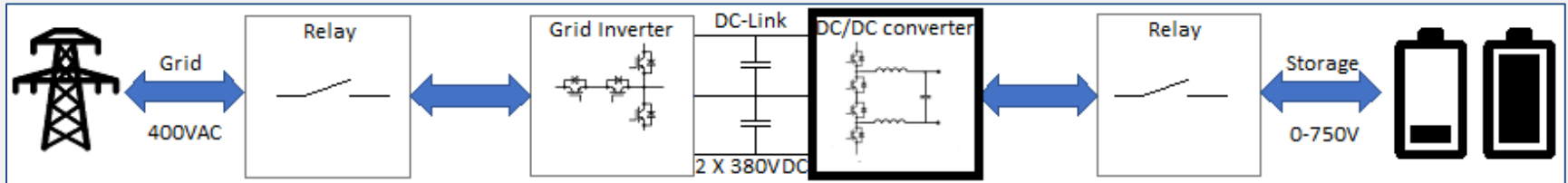
PASSION FOR  
POWER ELECTRONICS

Design and manufacturing of  
customized power electronics

**CONVERDAN**  
ENGINEERING

# E-MOBILITY PILOT DEMONSTRATOR

## Grid-connected Battery Conditioner



- Charge and discharge of high voltage Li-Ion or LiFePO batteries with a minimum of energy loss.
- Enables energy efficient conditioning of the batteries during daily charging, battery stack manufacturing and potentially for grid support in a smart grid installation.

# TECHNICAL OVERVIEW

## Grid

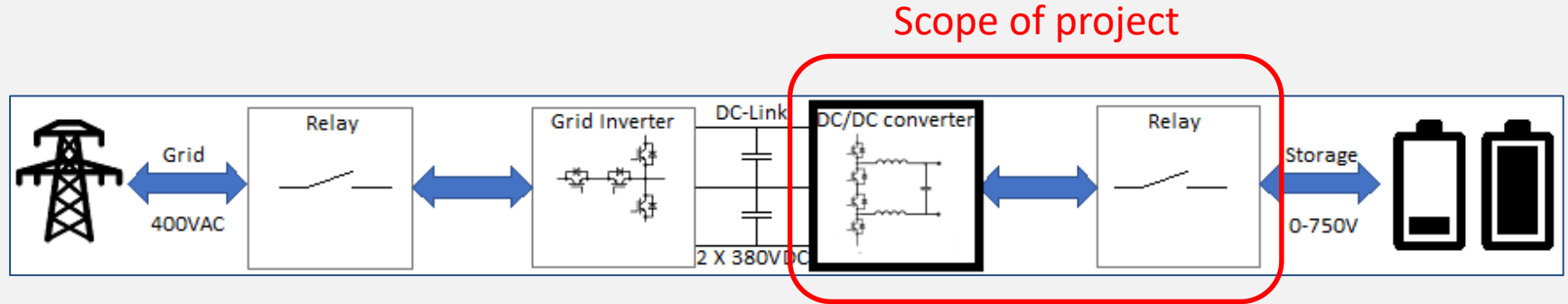
Nominal power (charge/discharge):	7.5 kW
Maximum grid current:	13 Arms
Grid connection type:	L1, L2, L3 + PE
Grid voltage range (including tolerances):	3 x 360 – 460 Vac
Grid frequency:	47 – 65 Hz

## Battery Interface

Suited for series connection of:	192 cells up to app. 100 Ah rating
Protection and disconnect:	DC fuse in battery +, inrush limitation
Cut-off Voltage:	2.8 V/cell
Maximum Charging Voltage:	3.6 V/cell
DC voltage charge/discharge (full power):	537 V – 691 V



# PROJECT FOCUS



Design and prototyping of:

- Bi-directional DC/DC converter based on SiC MOSFETS
- Inrush control for connecting to storage bank

# SiC CASCODES

Devices from: United Silicon Carbide (<https://unitedsic.com/cascodes/>)

How do SiC Cascodes work?

$$\text{JFET } V_{GS} = -\text{MOSFET } V_{DS}$$

Turn On

MOSFET turns "On"

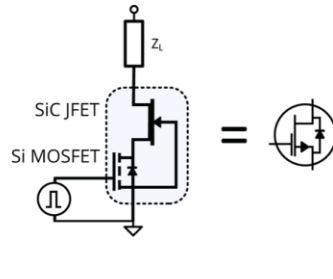
MOSFET  $V_{GS} > \text{MOSFET } V_{TH}$

MOSFET  $V_{DS} = 0 \text{ V}$

JFET turns "On"

MOSFET  $V_{DS} = 0 \text{ V}$ , JFET  $V_{GS} = 0 \text{ V}$

JFET  $V_{TH}$  is  $-6 \text{ V}$  typical



Low voltage MOSFET controls a 1.2kV JFET

Turn Off

MOSFET turns "Off"

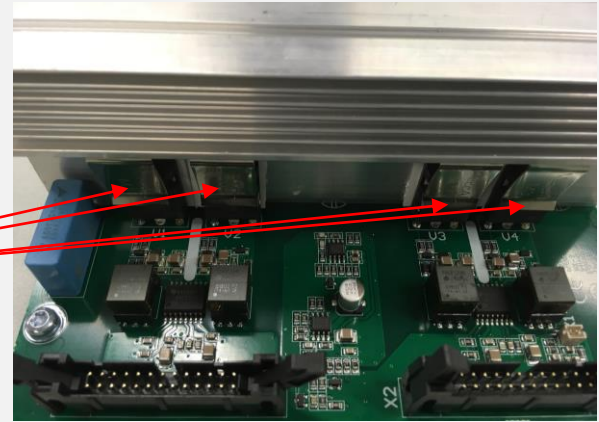
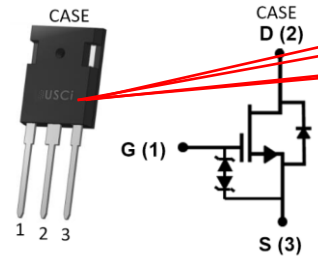
MOSFET  $V_{GS} < \text{MOSFET } V_{TH}$

MOSFET "Off",  $V_{DS}$  rises  $> 6 \text{ V}$

V

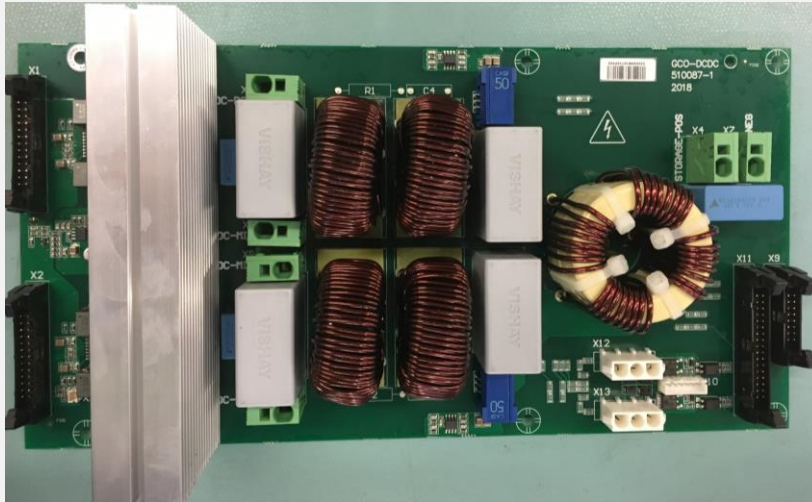
JFET turns "Off"

High Voltage Across JFET  $V_{DS}$

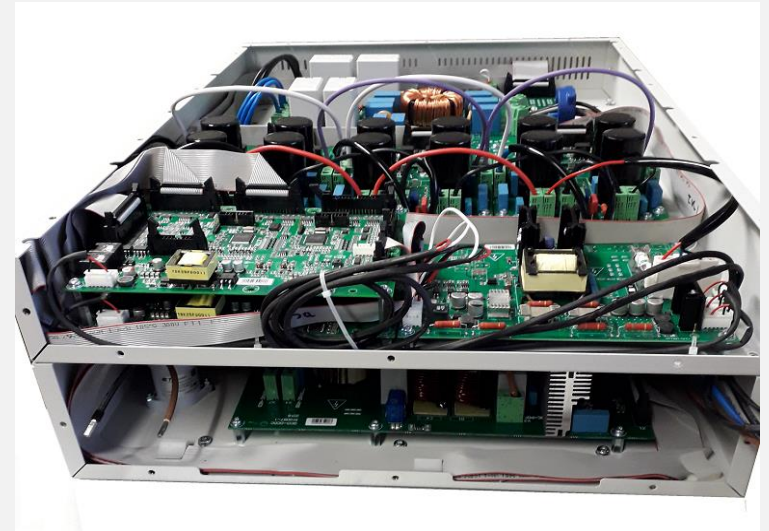


# PROTOTYPE

## DC/DC Converter Board



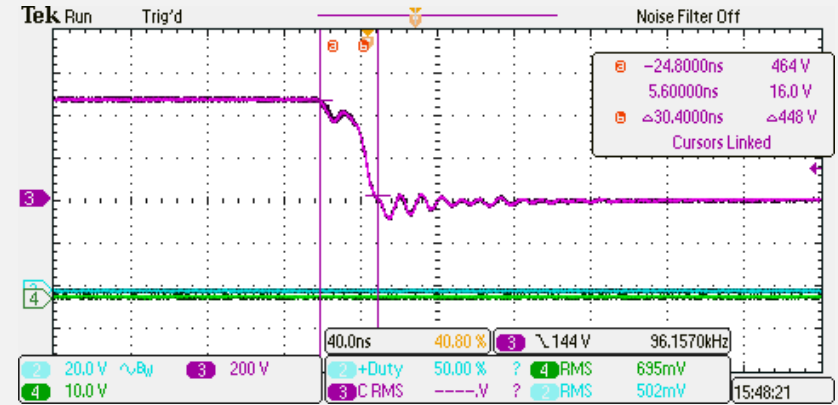
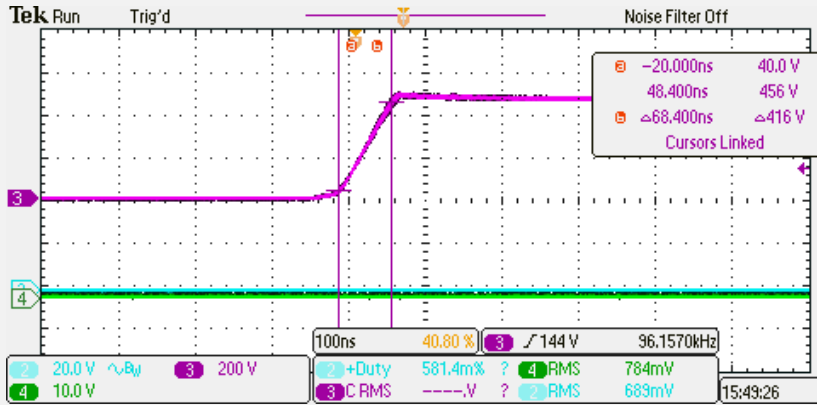
## Complete Unit





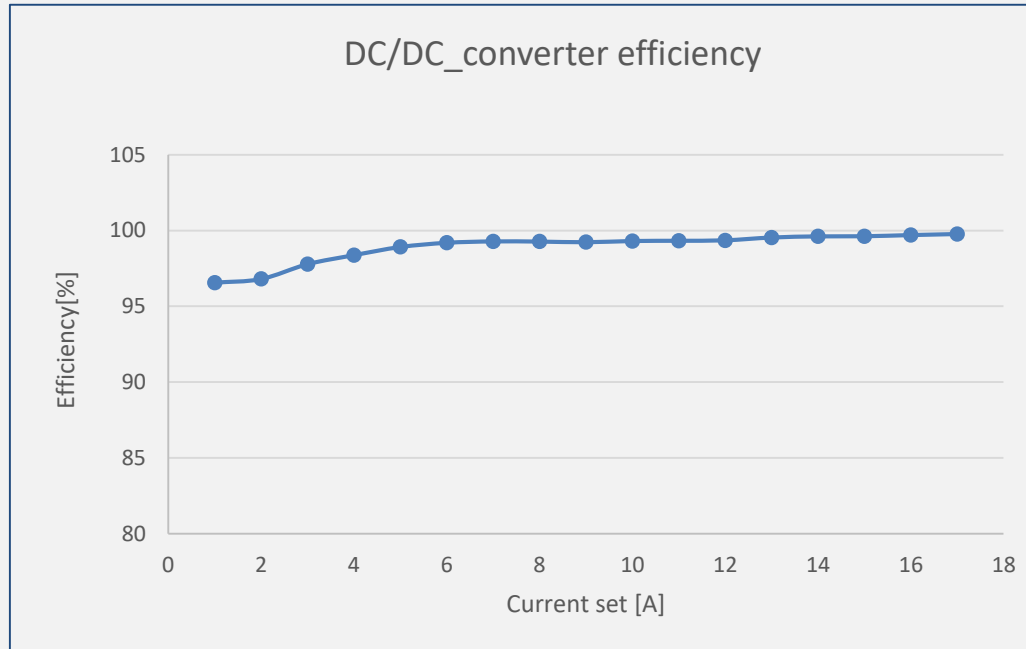
# SWITCHING PERFORMANCE

Very fast switching allows high efficiency



Low to moderate tendency for ringing/oscillations

# EFFICIENCY MEASUREMENTS





# FINDINGS & CONCLUSION

- SiC devices have both low switching losses and low conduction losses
- SiC devices primarily available in industry standard TO247 package
  - Power modules with SiC chips are coming, but the selection is still very limited
- Measuring equipment:
  - Very CMRR voltage probes required
  - Accuracy in measuring efficiency is difficult, due to very low losses

## Questions ?